

Electronic Acknowledgement Receipt

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International Application Number:	
Confirmation Number:	4644
Title of Invention:	Group-III nitride semiconductor device
First Named Inventor/Applicant Name:	Hiromitsu Sakai
Customer Number:	23373
Filer:	Abraham Jacob Rosner/Cora Flanagan
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Attorney Docket Number:	Q78084
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File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1		Q78084_IDS.PDF	141950	yes	4
			e9d78c7e16196408dc22e0c3952d82cc476c3		

Multipart Description/PDF files in .zip description					
Document Description			Start	End	
Transmittal Letter			1	2	
Information Disclosure Statement (IDS) Filed (5B/08)			3	4	
Warnings:					
Information:					
2	Foreign Reference	EP_1_160_882.PDF	2604628 08aab7117f4b5a5c0d581d396c17c9d83565c3f	no	16
Warnings:					
Information:					
3	NPL Documents	TAKEUCHI_ET_AL_Improvement_of_far-field_pattern_ETC.PDF	711227 d11823f0b0cc81170c7ee733368951a7a730228c6e	no	3
Warnings:					
Information:					
4	NPL Documents	ADELMANN_ET_AL_Atomic-layer_epitaxy_of_GaN_quantum_wells_ETC.PDF	942184 70aa7ba4f8b6b0b078802d89466081b9c3b95d	no	3
Warnings:					
Information:					
5	NPL Documents	MIYAMURA_ET_AL_Stranski-Krastanow_growth_of_GaN_quantum_dots_ETC.PDF	685343 e12ca94d8f6d2670a196db398c559d7d9936c51	no	4
Warnings:					
Information:					
6	NPL Documents	HUANG_ET_AL_Defect_reduction_with_quantum_dots_in_GaN_ETC.PDF	946272 66c28a1cacc053d91e054a0536ca1c7c0b2914	no	3
Warnings:					
Information:					
7	NPL Documents	Supplemental_European_Search_Report_EP04792622.PDF	676951 1464e9154475d3148026a17047e90136d223b1	no	5
Warnings:					
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Total Files Size (in bytes):			6708555		

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New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.

New International Application Filed with the USPTO as a Receiving Office

If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.